

HALOGEN

FREE



# High Voltage 4 $\Omega$ Quad SPST CMOS Analog Switch

#### **DESCRIPTION**

The DG454 series has four independently selectable high voltage (44 V) SPST switches, each with a typical on resistance of 4  $\Omega$  and a typical flatness of 0.2  $\Omega$ , ideal parameters for low distortion audio signal switching.

The DG454 (NC) and DG455 (NO) are identical except for the digital logic control input, which is inverted as shown in the Truth Table. The DG456 has two normally closed and two normally open switches.

These are high voltage switches that are fully specified with dual supplies at  $\pm$  5 V and  $\pm$  15 V and a single supply of 12 V.

Fast switching speeds coupled with high signal bandwidth makes these parts suitable for video switching applications.

All digital inputs have 0.8 V and 2.4 V logic thresholds ensuring low voltage TTL/CMOS compatibility. Each switch conducts equally well in both directions when on and can handle an input signal range that extends to the supply voltage rails.

The DG454 DG455 and DG456 are pin compatible with the DG411, DG412 and DG413, except they require no  $V_L$  supply.

#### **FEATURES**

- Low on-resistance (4 Ω typical)
- On-resistance flatness (0.2 Ω typical)
- 100 mA continuous current
- 44 V supply maximum rating
- ± 15 V analog signal range
- Fully specified at supply voltages of ± 5 V, 12 V and ± 15 V
- No V<sub>L</sub> required
- · Fast switching speed:
  - t<sub>on</sub> 80 ns
  - t<sub>off</sub> 60 ns
- TTL/CMOS compatible
- ESD protection 2 kV
- Pin compatible with DG411, DG412, and DG413, except no V<sub>I</sub> required
- Material categorization: For definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

### **APPLICATIONS**

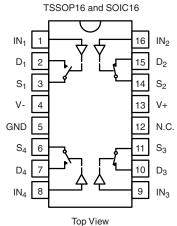
- · Audio and video signal switching
- · Precision automatic test equipment
- · Precision data acquisition
- · Relay replacement
- Communications systems
- Automotive and avionics applications
- Sample and hold systems

#### **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**

### DG454 TSSOP16 and SOIC16 $IN_2$ IN<sub>1</sub> $D_2$ D<sub>1</sub> $S_1$ V-GND N C $S_4$ $S_3$ $D_4$ $D_3$ $IN_4$ $IN_3$ Top View

TRUTH TABLE								
Logic	DG454	DG455						
0	On	Off						
1	Off	On						

# DG456



TRUTH TABL	E	
Logic	SW <sub>1</sub> , SW <sub>4</sub>	SW <sub>2</sub> , SW <sub>3</sub>
0	Off	On
1	On	Off

# DG454, DG455, DG456

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ORDERING INFORMATION								
Temp. Range	Package	Part Number						
DG454, DG455, DG456								
40 °C to 405 °C	16 Pin TSSOP	DG454EQ-T1-E3 DG455EQ-T1-E3 DG456EQ-T1-E3						
- 40 °C to 125 °C <sup>a</sup>	16 Pin Narrow SOIC	DG454EY-T1-E3 DG455EY-T1-E3 DG456EY-T1-E3						

#### Notes:

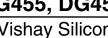
a. - 40 °C to 85 °C datasheet limits apply.

Parameter		Limit	Unit	
V+ to V-		44		
GND to V-		25	V	
Digital Inputs <sup>a</sup> , V <sub>S</sub> , V <sub>D</sub>		(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first	]	
Continuous Current (D, S only)		100	mA	
Peak Current, S or D (Pulsed 1 ms, 10 %	6 Duty Cycle)	300		
Storage Temperature		- 65 to 150	°C	
Daniel Disciplina (Daniel Daniel	16 Pin TSSOP <sup>c</sup>	450	m\\\	
Power Dissipation (Package) <sup>b</sup>	16 Pin Narrow SOIC <sup>d</sup>	600	mW	
Ti 15 :: (5 ! )b	16 Pin TSSOP	178	°C/M	
Thermal Resistance (Package) <sup>D</sup>	16 Pin Narrow SOIC	125	°C/W	
ESD (HBM)	<u>.</u>	2	kV	

## Notes:

- $a. \ Signals \ on \ S_X, \ D_X, \ or \ IN_X \ exceeding \ V+ \ or \ V- \ will \ be \ clamped \ by \ internal \ diodes. \ Limit forward \ diode \ current \ to \ maximum \ current \ ratings.$
- b. All leads welded or soldered to PC board.
- c. Derate 5.6 mW/°C above 70 °C.
- d. Derate 8 mW/°C above 75 °C.

SPECIFICATIONS FOR DUAL SUPPLIES										
	Cumahal	Test Conditions Unless Specified			- 40 °C t	o 125 °C	- 40 °C	to 85 °C		
Parameter	Symbol	V+ = 15 V, V- = - 15 V V <sub>IN</sub> = 2.4 V, 0.8 V <sup>a</sup>	Temp. <sup>b</sup>	Typ. <sup>c</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Unit	
Analog Switch					•					
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full		- 15	15	- 15	15	٧	
On-Resistance	R <sub>ON</sub>	$I_S = -10 \text{ mA}, V_D = -10 \text{ V to} + 10 \text{ V}$	Room Full	3.8		5.3 8.3		5.3 7.3		
On-Resistance Match	ΔR <sub>ON</sub>	$I_S = -10 \text{ mA}, V_D = \pm 10 \text{ V}$	Room Full	0.12		0.5 1		0.5 0.5	Ω	
On-Resistance Flatness	R <sub>FLATNESS</sub>	I <sub>S</sub> = - 10 mA, V <sub>D</sub> = - 5 V, 0 V, + 5 V	Room Full	0.25		0.5 0.5		0.5 0.5		
Switch Off	I <sub>S(off)</sub>	V 40VV 40V	Room Full	± 0.1	- 0.5 - 20	0.5 20	- 0.5 - 2.5	0.5 2.5		
Leakage Current	I <sub>D(off)</sub>	$V_D = \pm 10 \text{ V}, V_S = 10 \text{ V}$	Room Full	± 0.1	- 0.5 - 20	0.5 20	- 0.5 - 2.5	0.5 2.5	nA	
Channel On Leakage Current	I <sub>D(on)</sub>	$V_S = V_D = \pm 10 \text{ V}$	Room Full	± 0.1	- 1 - 40	1 40	- 1 - 5	1 5		





Parameter	Symbol	Test Conditions Unless Specified	Temp.b	b T C	- 40 °C to 125 °C		- 40 °C	to 85 °C	Unit
raiametei	Symbol	V+ = 15 V, V- = - 15 V V <sub>IN</sub> = 2.4 V, 0.8 V <sup>a</sup>	remp.	Typ. <sup>c</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Oiiii
Digital Control						L		L	ı
Input Current, V <sub>IN</sub> Low	I <sub>IL</sub>	V <sub>IN</sub> Under Test = 0.8 V	Full	0.005	- 0.5	0.5	- 0.5	0.5	
Input Current, V <sub>IN</sub> High	I <sub>IH</sub>	V <sub>IN</sub> Under Test = 2.4 V	Full	0.005	- 0.5	0.5	- 0.5	0.5	μΑ
Input Capacitance <sup>e</sup>	C <sub>IN</sub>	f = 1 MHz	Room	7					pF
<b>Dynamic Characteristics</b>									
Turn-On Time	t <sub>ON</sub>	$R_L = 300 \Omega$ , $C_L = 35 pF$	Room Full	88		118 160		118 144	
Turn-Off Time	t <sub>OFF</sub>	$V_S = \pm 10 \text{ V}$ , See Figure 2	Room Full	69		97 120		97 112	ns
Break-Before-Make Time Delay	t <sub>D</sub>	DG456 only, $V_S = 10 \text{ V}$ $R_L = 300 \Omega$ , $C_L = 35 \text{ pF}$	Room	18					
Charge Injection <sup>e</sup>	Q	$V_g = 0 \text{ V, } R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room	22					рС
Off Isolation <sup>e</sup>	OIRR	$R_1 = 50 \Omega, C_1 = 5 pF$	Room	- 60					
Channel-to-Channel Crosstalk <sup>e</sup>	X <sub>TALK</sub>	f = 1 MHz	Room	- 85					dB
Source Off Capacitance <sup>e</sup>	C <sub>S(off)</sub>		Room	31					
Drain Off Capacitance <sup>e</sup>	C <sub>D(off)</sub>	f = 1 MHz	Room	34					pF
Channel On Capacitance <sup>e</sup>	C <sub>D(on)</sub>		Room	103					
Total Harmonic Distortion <sup>e</sup>	THD	Signal = 5 $V_{RMS}$ , 20 Hz to 20 kHz, $R_L = 600 \Omega$	Room	0.04					%
Power Supplies		<u> </u>			1	l		l .	L
Power Supply Current	l+		Room Full	25		100 100		100 100	
Negative Supply Current	l-	V+ = 16.5 V, V- = - 16.5 V V <sub>IN</sub> = 0 or 5 V	Room Full	- 0.001	- 0.5 - 5		- 0.5 - 5		μΑ
Ground Current	$I_{GND}$		Room Full	- 25	- 100 - 100		- 100 - 100		

SPECIFICATIONS FOR DUAL SUPPLIES									
Parameter	Symbol	Test Conditions Unless Specified		_	- 40 °C t	o 125 °C	- 40 °C to 85 °C		Unit
raiametei	Syllibol	V+ = 5 V, V- = -5 V $V_{IN} = 2.4 V, 0.8 V^{a}$	Temp.b	Typ. <sup>c</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Offic
Analog Switch									
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full		- 5	5	- 5	5	٧
On-Resistance	R <sub>ON</sub>	V+ = + 5 V, V- = -5 V $I_S = -10 \text{ mA}, V_D = -3.5 V \text{ to} + 3.5 V$	Room Full	3.8		11 15		11 12	Ω
On-Resistance Match	ΔR <sub>ON</sub>	V+ = + 5 V, V- = -5 V, $I_S = -10 \text{ mA}, V_D = \pm 3.5 V$	Room Full	0.13		0.5 1		0.5 0.5	22
Dynamic Characteristics	3								
Turn-On Time <sup>e</sup>	t <sub>ON</sub>	$R_L = 300 \Omega$ , $C_L = 35 pF$	Room Full	170		200 296		200 256	
Turn-Off Time <sup>e</sup>	t <sub>OFF</sub>	$V_S = 3 V$ , See Figure 2	Room Full	66		96 124		96 113	ns
Break-Before-Make <sup>e</sup> Time Delay	t <sub>D</sub>	DG456 only, $V_S = 3 \text{ V}$ $R_L = 300 \Omega$ , $C_L = 35 \text{ pF}$	Room	98					
Charge Injection <sup>e</sup>	Q	$V_g = 0 \text{ V, } R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room	8					рC

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SPECIFICATIONS	SPECIFICATIONS FOR DUAL SUPPLIES										
Parameter	Symbol	Test Conditions Unless Specified	Temp.b	Typ. <sup>c</sup>	- 40 °C to 125 °C - 40 °C to 85 °C			to 85 °C	Unit		
		V+ = 5 V, V- = -5 V $V_{IN} = 2.4 V, 0.8 V^{a}$			Min. <sup>d</sup>	Max. <sup>d</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>			
Power Supplies											
Power Supply Current	l+		Room Full	14		100 100		100 100			
Negative Supply Current	l-	$V_{IN} = 0 \text{ or } 5 \text{ V}$	Room Full	- 0.001	- 0.5 - 5		- 0.5 - 5		μΑ		
Ground Current	I <sub>GND</sub>		Room Full	- 14	- 100 - 100		- 100 - 100				

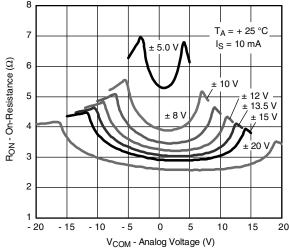
SPECIFICATIONS FOR UNIPOLAR SUPPLIES									
Parameter	Symbol	Test Conditions Unless Specified	Temp.b	b Typ.c	- 40 °C to 125 °C		- 40 °C	to 85 °C	Unit
Tarameter	Cymbol	V+ = 12 V, V- = 0 V V <sub>IN</sub> = 2.4 V, 0.8 V <sup>a</sup>	remp.	Typ.	Min. <sup>d</sup>	Max. <sup>d</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	
Analog Switch									
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full			12		12	٧
On-Resistance	R <sub>ON</sub>	$I_S = -10 \text{ mA}, V_D = 0 \text{ V to} + 10 \text{ V}$	Room Full	5.5		8.1 12.4		8.1 10.4	
On-Resistance Match	ΔR <sub>ON</sub>	I <sub>S</sub> = - 10 mA, V <sub>D</sub> = + 10 V	Room Full	0.14		0.5 1		0.5 0.5	Ω
On-Resistance Flatness	R <sub>FLATNESS</sub>	I <sub>S</sub> = - 10 mA, V <sub>D</sub> = 0 V, + 5 V, + 10 V	Room Full	0.94		1.5 1.7		1.5 1.5	
Dynamic Characteristics									
Turn-On Time	t <sub>ON</sub>	$R_L = 300 \Omega, C_L = 35 pF$	Room Full	132		162 238		162 210	
Turn-Off Time	t <sub>OFF</sub>	V <sub>S</sub> = 8 V, See Figure 2	Room Full	61		91 117		91 105	ns
Break-Before-Make Time Delay	t <sub>D</sub>	DG456 only, $V_S = 8 \text{ V}$ $R_L = 300 \Omega$ , $C_L = 35 \text{ pF}$	Room	70					
Charge Injection <sup>e</sup>	Q	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room	1					рС
Power Supplies	•		l		•	l .	ı		
Power Supply Current	I+		Room Full	25		100 100		100 100	
Negative Supply Current	I-	V+ = 13.5 V, V- = 0 V V <sub>IN</sub> = 0 or 5 V	Room Full	- 0.001	- 0.5 - 5		- 0.5 - 5		μΑ
Ground Current	I <sub>GND</sub>		Room Full	- 25	- 100 - 100		- 100 - 100		

- a.  $V_{IN}$  = input voltage to perform proper function.
- b. Room = 25  $^{\circ}$ C, Full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e. Guaranteed by design, not subject to production test.

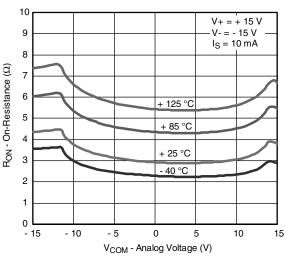
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



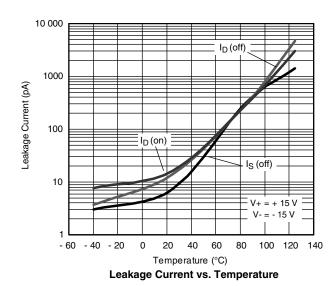
## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



## On-Resistance vs. V<sub>D</sub> and Dual Supply Voltage

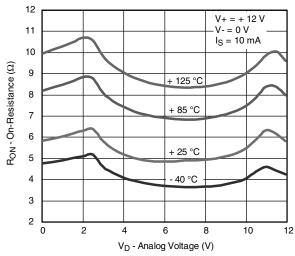


On-Resistance vs. V<sub>D</sub> and Temperature

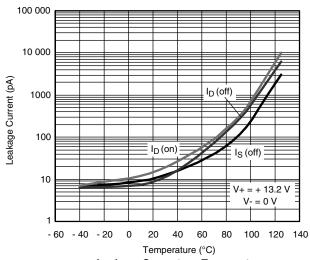


20  $T_A = + 25 \, ^{\circ}C$  $I_S = 10 \text{ mA}$ 15 R<sub>ON</sub> - On-Resistance (Ω) V+ = 5 V 10 V+ = 10.8 V + = 15 V 5 V + = 36 V0 12 20 28 V<sub>COM</sub> - Analog Voltage (V)

On-Resistance vs.  $V_{\text{D}}$  and Single Supply Voltage



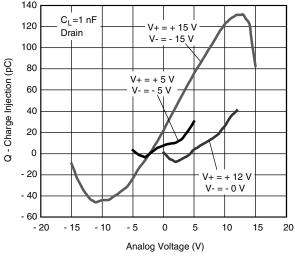
On-Resistance vs.  $V_{\text{D}}$  and Temperature



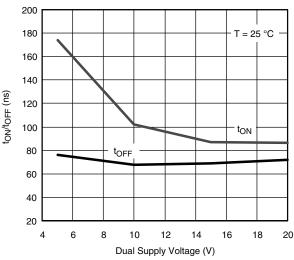
Leakage Current vs. Temperature

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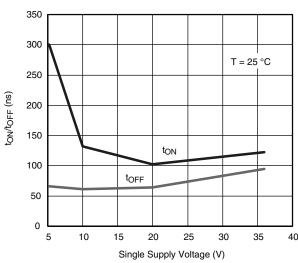
## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



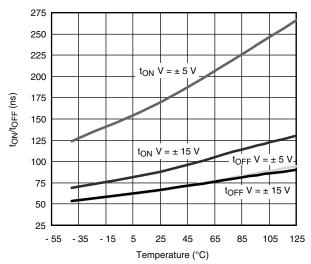
Charge Injection vs. Analog Voltage



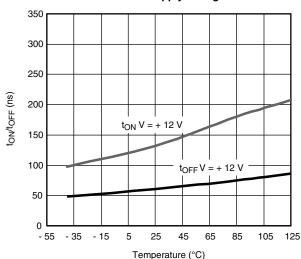
Switching Time vs. Dual Supply Voltage



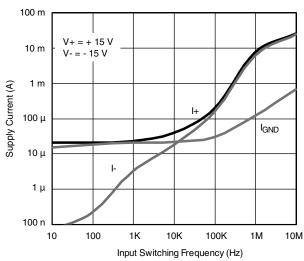
Switching Time vs. Single Supply Voltage



Switching Time vs. Temperature and **Dual Supply Voltage** 



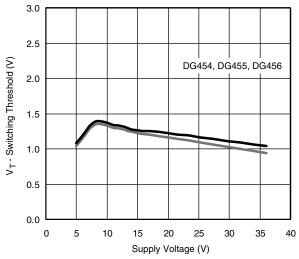
Switching Time vs. Temperature and Single Supply Voltage



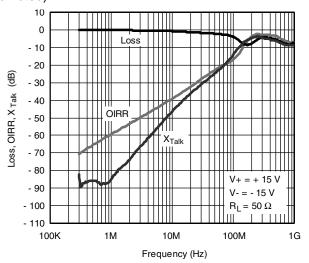
Supply Current vs. Input Switching Frequency



## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

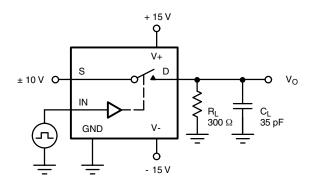


Switching Threshold vs. Supply Voltage



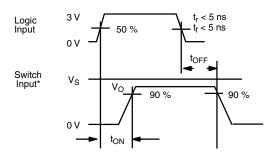
Insertion Loss, Off-Isolation, Crosstalk vs. Frequency

### **TEST CIRCUITS**



C<sub>L</sub> (includes fixture and stray capacitance)

$$V_O = V_S$$
 
$$\frac{R_L}{R_L + R_{DS(on)}}$$



Note: Logic input waveform is inverted for switches that have the opposite logic sense control

Figure 1. Switching Time

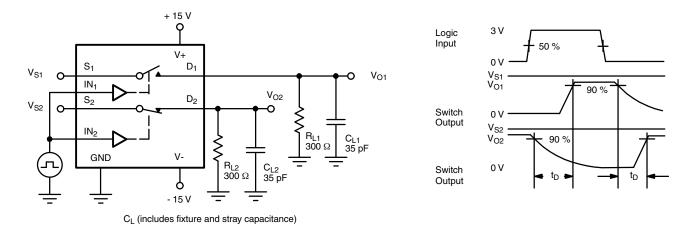


Figure 2. Break-Before-Make (DG456)

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## **TEST CIRCUITS**



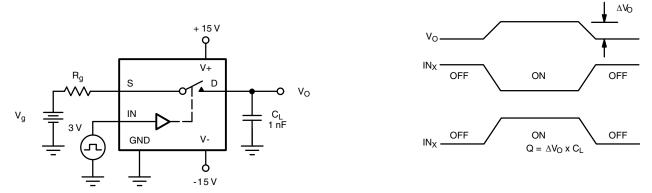


Figure 3. Charge Injection

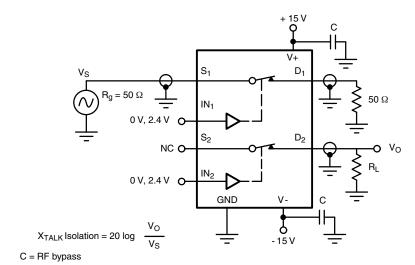
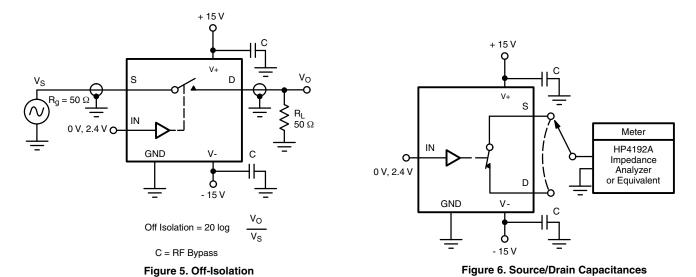


Figure 4. Crosstalk



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?74473.



SOIC (NARROW): 16-LEAD JEDEC Part Number: MS-012



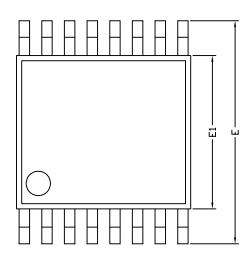
	MILLIM	IETERS	INC	HES				
Dim	Min	Max	Min	Max				
Α	1.35	1.75	0.053	0.069				
A <sub>1</sub>	0.10	0.20	0.004	0.008				
В	0.38	0.51	0.015	0.020				
С	0.18	0.23	0.007	0.009				
D	9.80	10.00	0.385	0.393				
E	3.80	4.00	0.149	0.157				
е	1.27	BSC	0.050	BSC				
Н	5.80	6.20	0.228	0.244				
L	0.50	0.93	0.020	0.037				
0	0°	8°	0°	8°				
ECN: S-0	ECN: S-03946—Rev. F, 09-Jul-01							

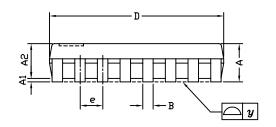
DWG: 5300





**TSSOP: 16-LEAD** 







	DII	MENSIONS IN MILLIMETER	RS
Symbols	Min	Nom	Max
А	-	1.10	1.20
A1	0.05	0.10	0.15
A2	-	1.00	1.05
В	0.22	0.28	0.38
С	-	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
е	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
у	-	-	0.10
θ1	0°	3°	6°
FCN: S-61920-Bev D 23-	Oct-06	<u>.</u>	

ECN: S-61920-Rev. D, 23-Oct-06

DWG: 5624

Document Number: 74417
23-Oct-06
www.vishay.com



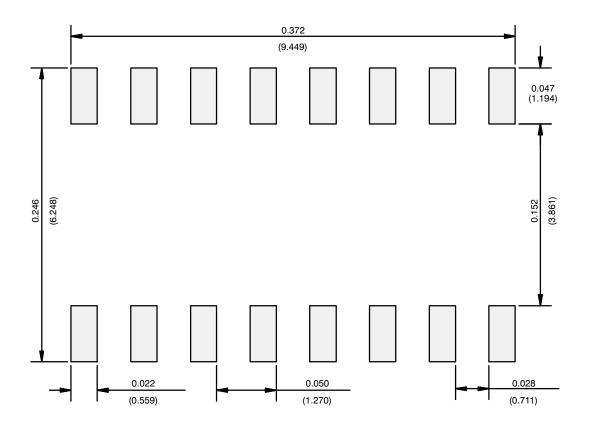
## **RECOMMENDED MINIMUM PAD FOR TSSOP-16**



Recommended Minimum Pads Dimensions in inches (mm)



## **RECOMMENDED MINIMUM PADS FOR SO-16**



Recommended Minimum Pads Dimensions in Inches/(mm)

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# **Legal Disclaimer Notice**

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